



International Conference on Particle Physics and
Astrophysics

SiPM Geiger discharge for high intensity light registration

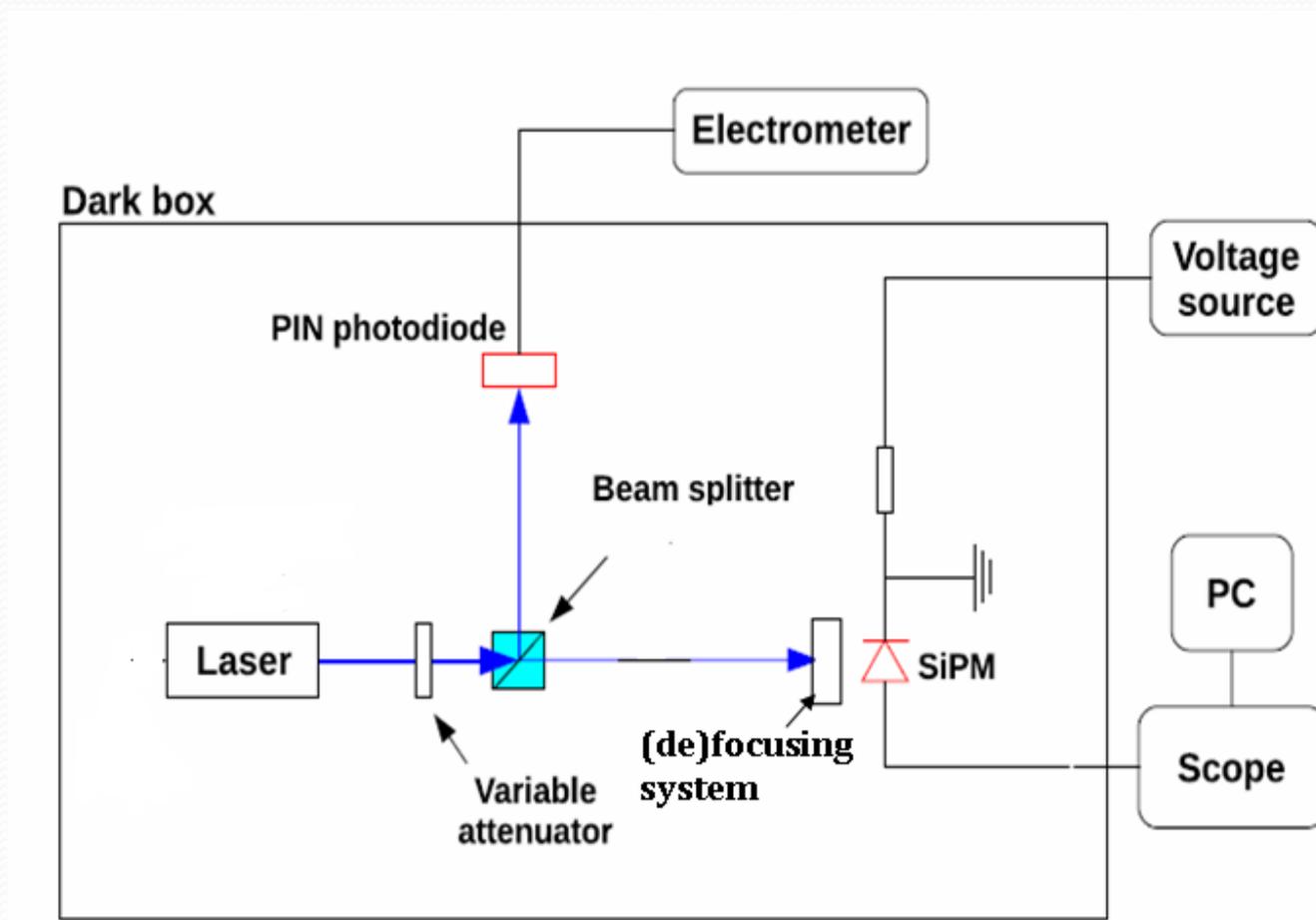
P.Buzhan, E.Popova, A.Ilyin, A.Stifutkin

October 5-10, 2015
Moscow

*National Research Nuclear University MEPhI
(Moscow Engineering Physics Institute), Moscow,
Russia*

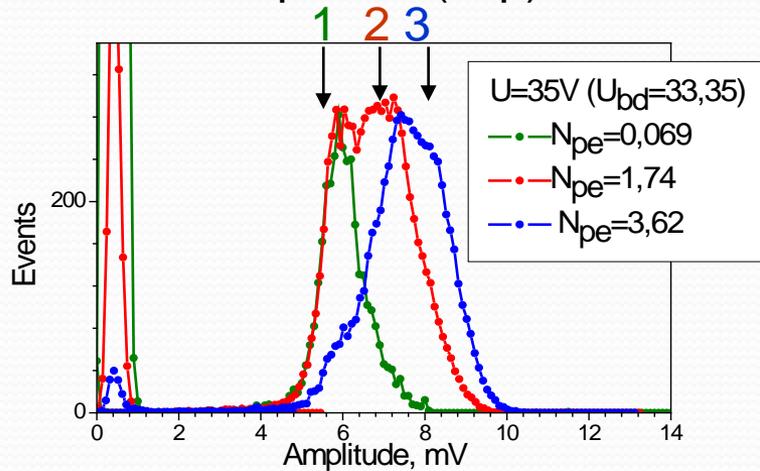
*P. Buzhan et al. "SiPM Geiger
discharge ..."*

Measurement setup with 40ps laser 405nm, digital scope 2GHz with light intensity control

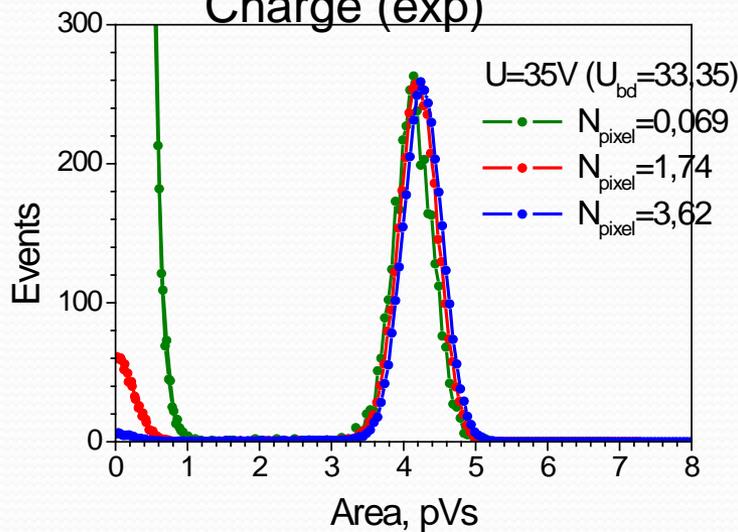


Fixed overvoltage $\Delta U=1.65V$, different light intensity

Amplitude (exp)

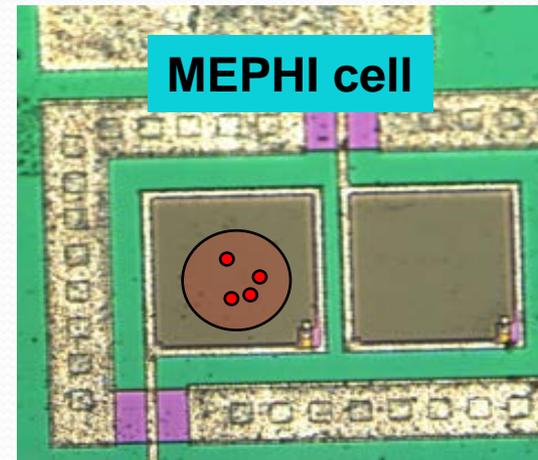


Charge (exp)

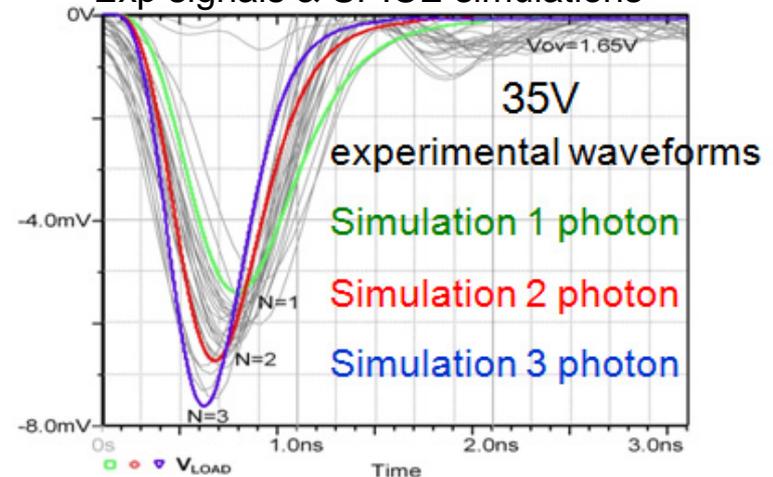


We have developed a SPICE model of Geiger discharge propagation

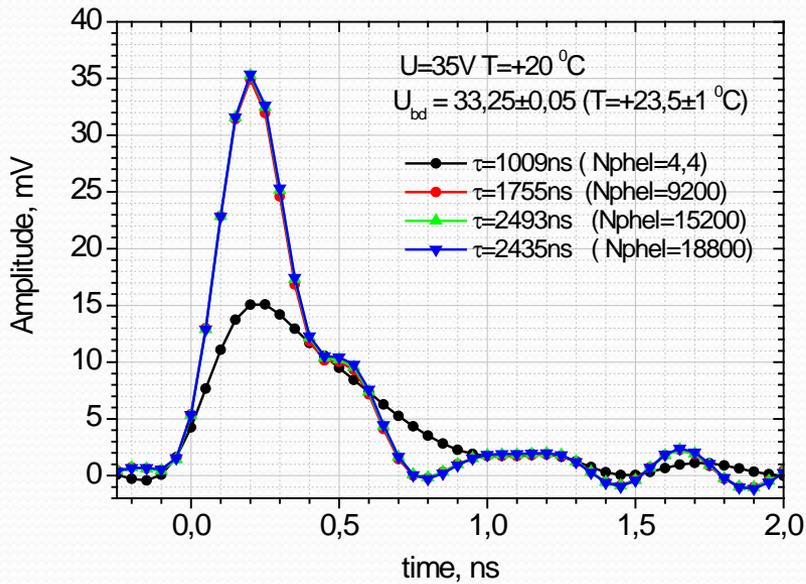
NIM A **787**, 1 July 2015, 270–274



Exp signals & SPICE simulations



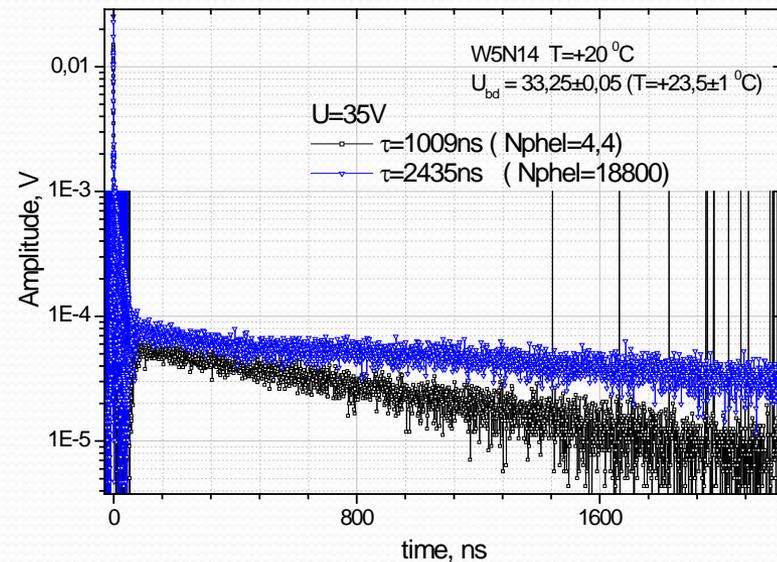
Single cell pulses for different intensity light but for fixed overvoltage. MEPHI cell (100x100 μm^2)



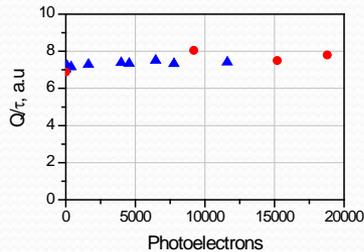
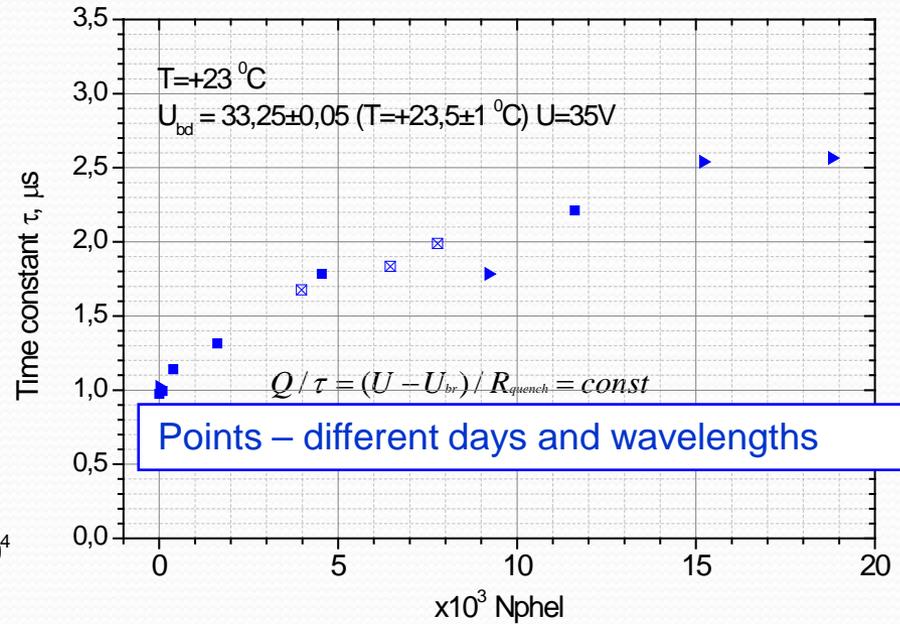
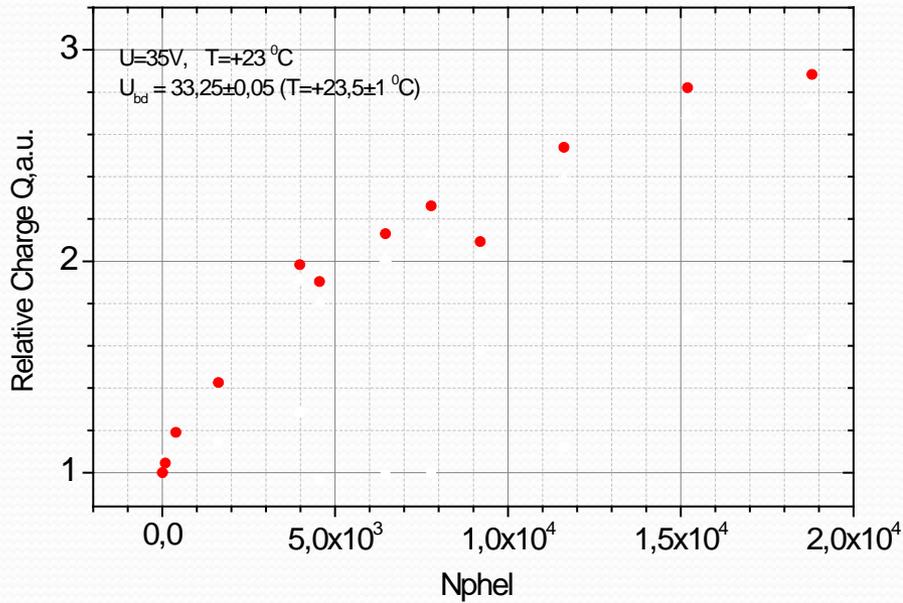
$$Q = (C_{fast} + C_{slow}) * (U - U_{br}) \quad \text{Total charge}$$

$$\tau = R_{quench} * (C_{fast} + C_{slow})$$

$$Q / \tau = (U - U_{br}) / R_{quench}$$



MEPHI cell.



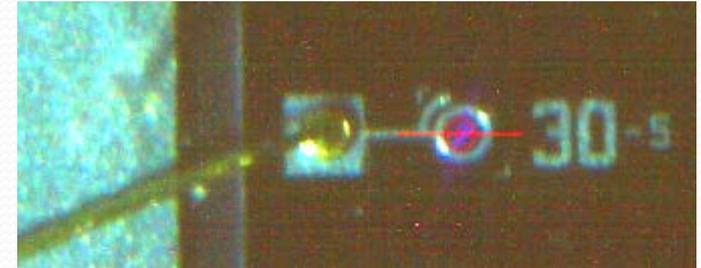
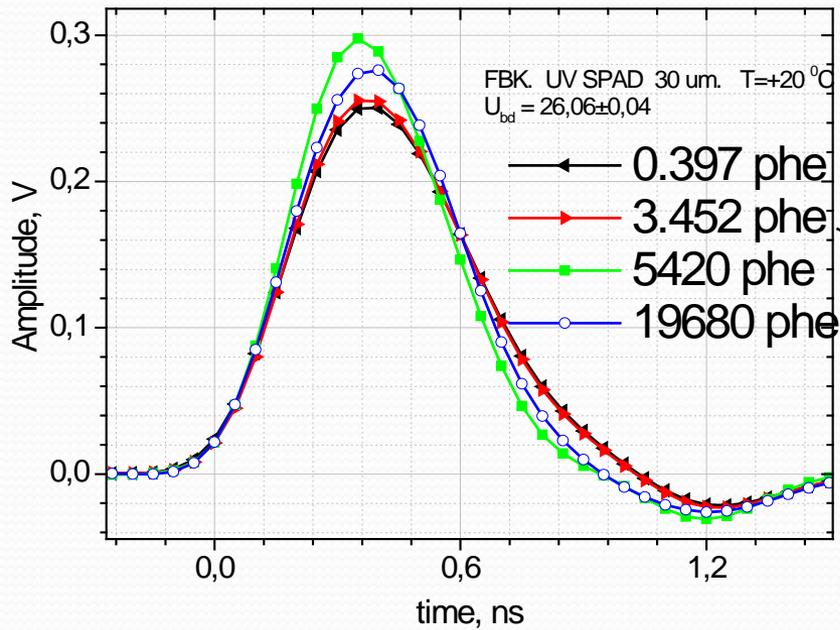
$$U - U_{br} = const$$

U-Ubreakdown doesn't change

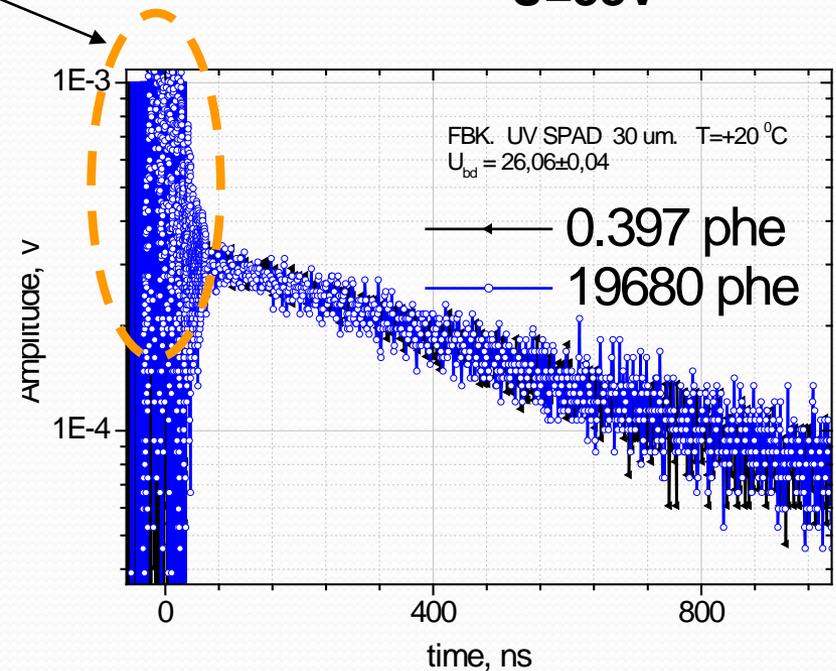
Q increases due to increasing of

$C_{fast} + C_{slow}$

Single cell pulses for different intensity light. FBK cell



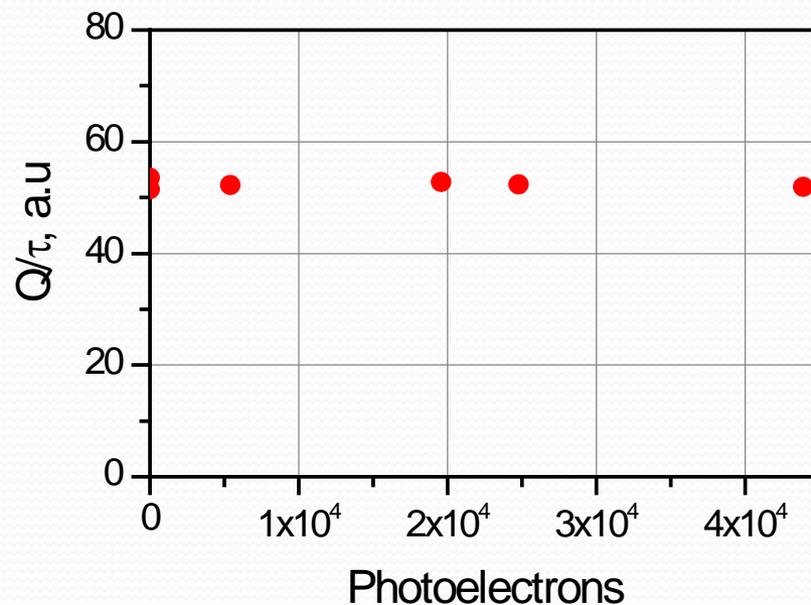
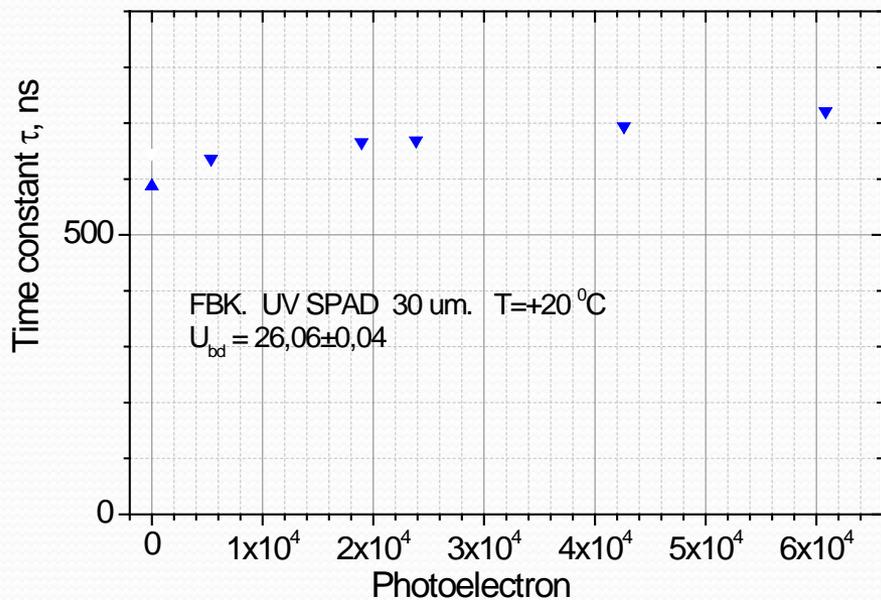
FBK cell. Dia 30 μm
 $U=38\text{V}$



Very small difference in pulse shapes for different light intensities

Single cell pulses for different intensity light. FBK cell

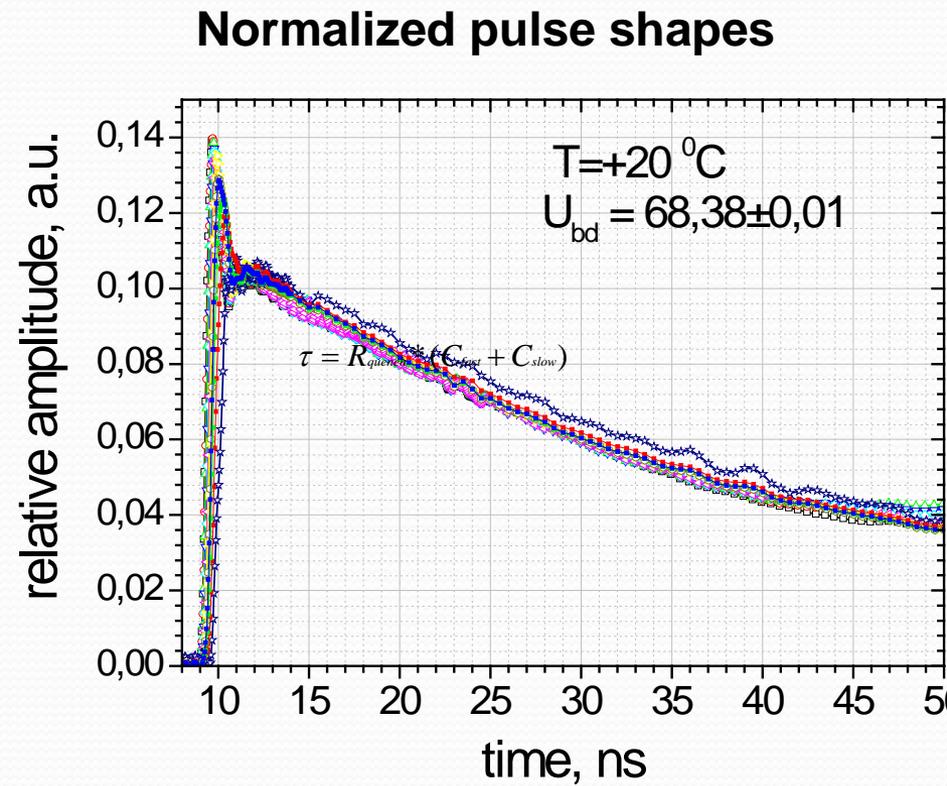
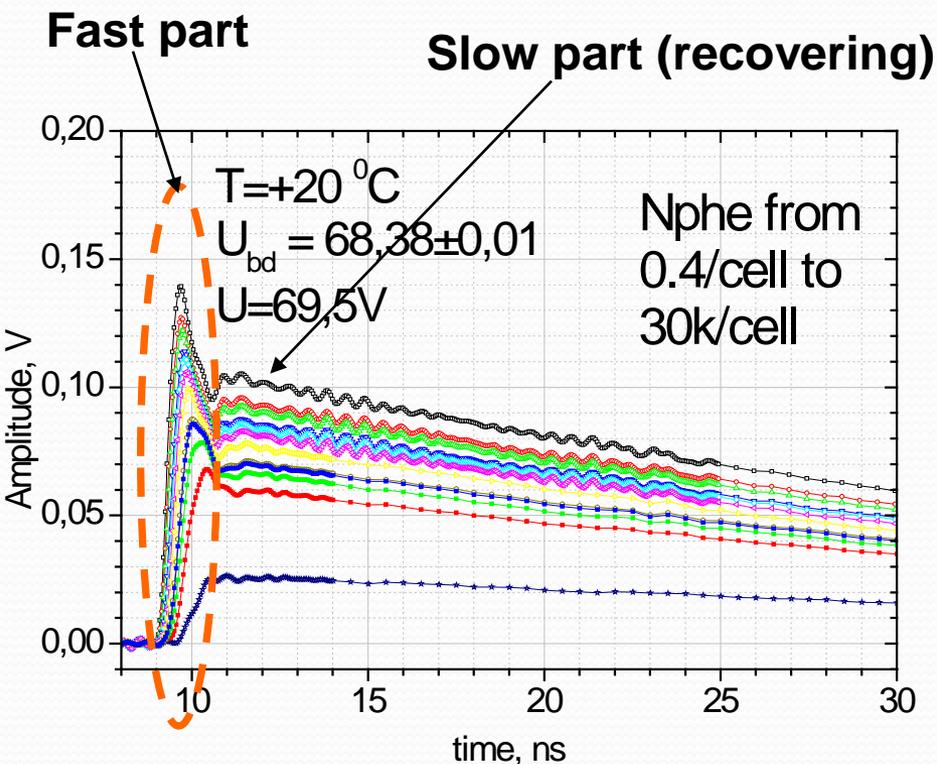
U=38V



U- $U_{breakdown}$ doesn't change
Q increases due to increasing of $C_{fast}+C_{slow}$

Pulse shape for different light Intensities. MEPHI data

Hamamatsu S10362-11-100U No.50



$Q = (C_{fast} + C_{slow}) * (U - U_{br})$ **Q changes with intensity**

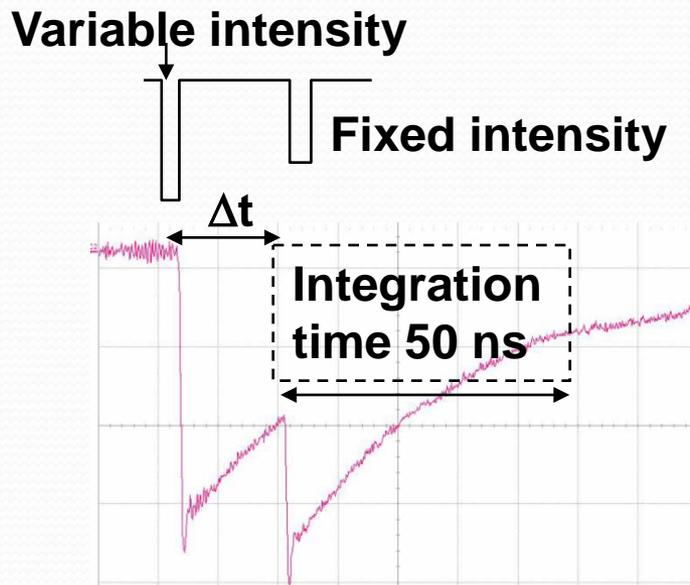
τ doesn't change with intensity

$A = N_{cell} * \Delta U / R_{quench}$

ΔU changes with intensity – voltage drops on cell p-n-junction below $U_{breakdown}$

Recovery time for different light Intensities. Double pulses

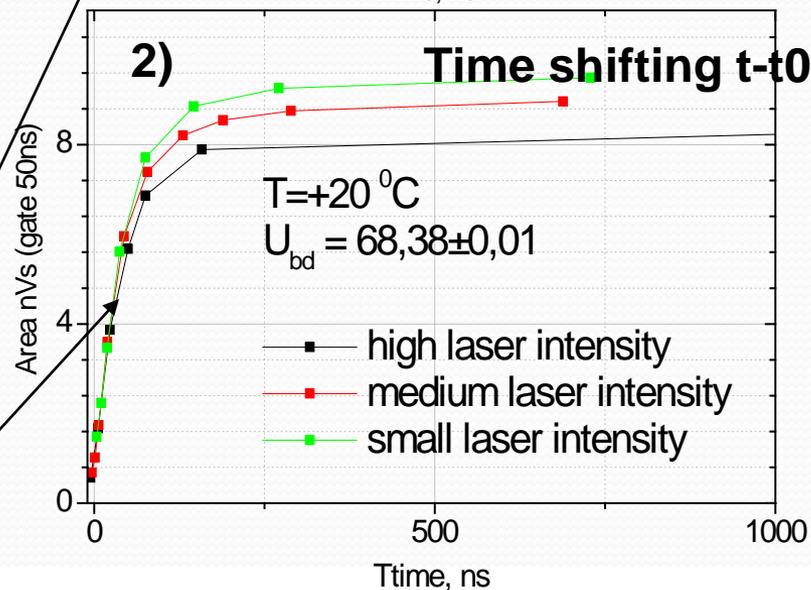
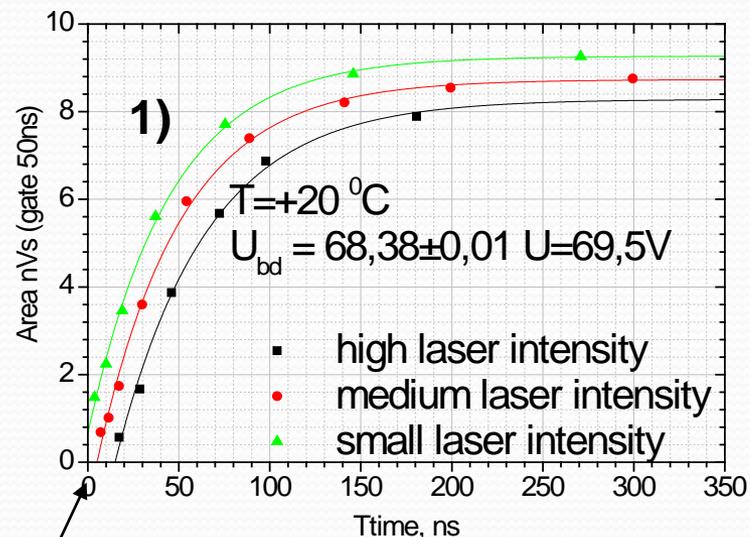
Hamamatsu S10362-11-100U No.50



Voltage on p-n-junction

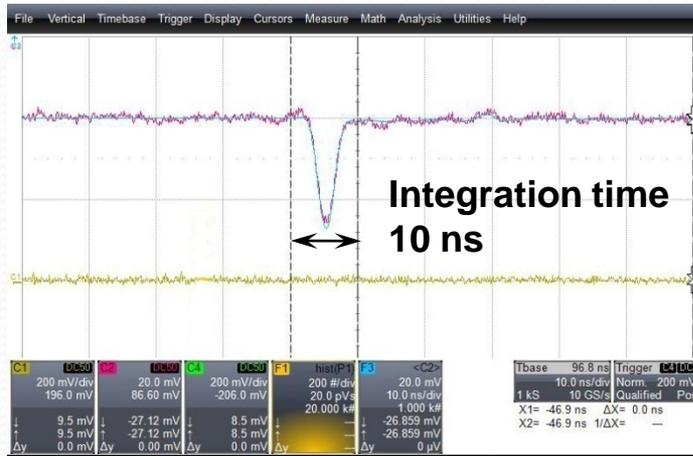


**As higher first pulse intensity
as longer time Δt before second pulse
starts to initiate Geiger discharge (1);
But recovery constant is the same (2)**

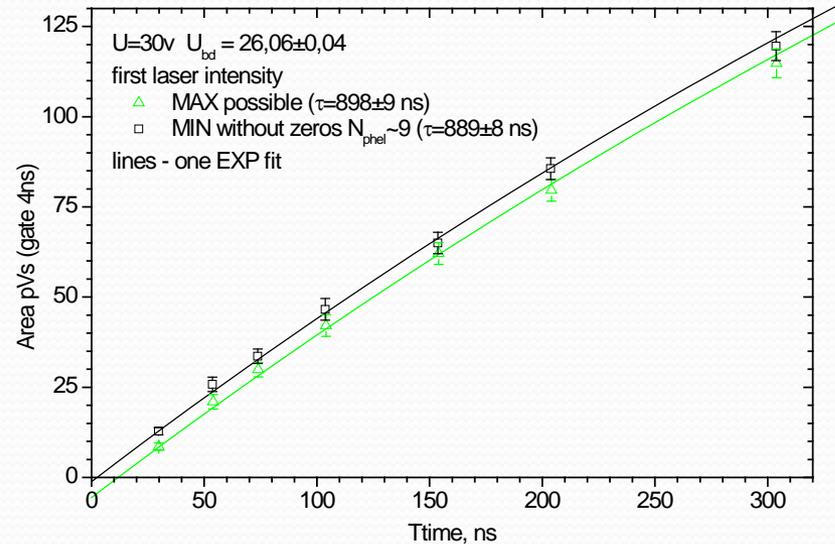


Recovery time for different light Intensities. Double pulses

Variable intensity



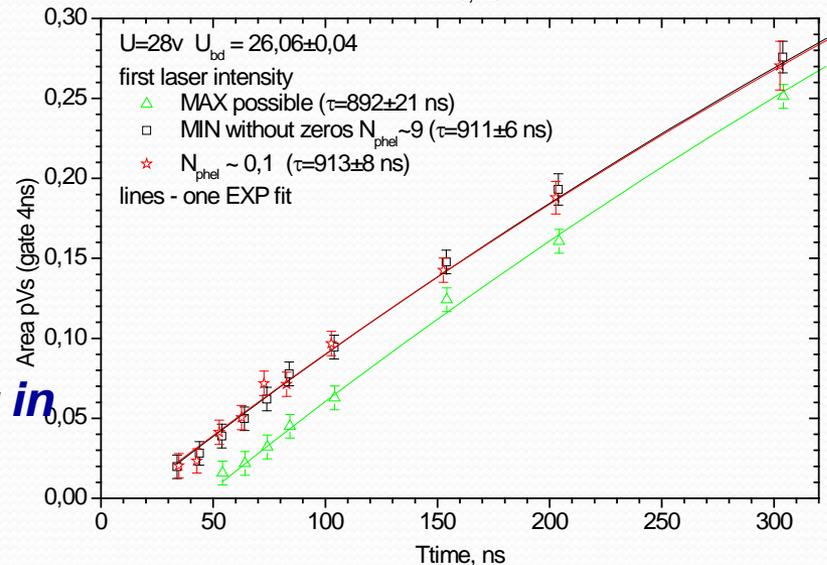
FBK cell



Voltage on p-n-junction



The lower overvoltage the grater a shift in start of the restoration



Summary:

- SiPM cell

 - recovery time

 - amplitude

 - charge

for Geiger mode operation in oversaturation conditions ($\gg 1$ phe/cell) depends on light intensity due to extremely fast developing of the Geiger discharge

- Depending on SiPM cell construction (technology used) high light intensity may affect cell capacity or/and voltage drop on cell pn-junction below $U_{\text{breakdown}}$

- The lower overvoltage the grater a shift in start of the SiPM cell restoration

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